


Features

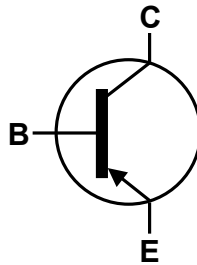
- $BV_{CEO} > -32V$
- $I_C = -2A$ high Continuous Current
- Low saturation voltage $V_{CE(sat)} < 800mV @ 2A$
- Complementary NPN Type: 2DD1766
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

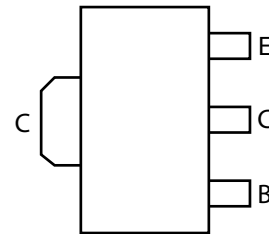
- Case: SOT89
- Case material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.052 grams (approximate)



Top View



Device Symbol



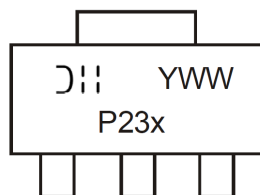
Pin Out – Top View

Ordering Information (Note 4)

| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|--------------|---------|--------------------|-----------------|-------------------|
| 2DB1188P-13 | P23P | 13 | 12 | 2,500 |
| 2DB1188Q-13 | P23Q | 13 | 12 | 2,500 |
| 2DB1188Q-13R | P23Q | 13 | 12 | 4,000 |
| 2DB1188R-13 | P23R | 13 | 12 | 2,500 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information



P23x = Product Type Marking Code
 Where P23P = 2DB1188P
 P23Q = 2DB1188Q
 P23R = 2DB1188R

D = Manufacturers' code marking
 YWW = Date Code Marking
 Y = Last Digit of Year (ex: 1 = 2011)
 WW = Week Code (01 – 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

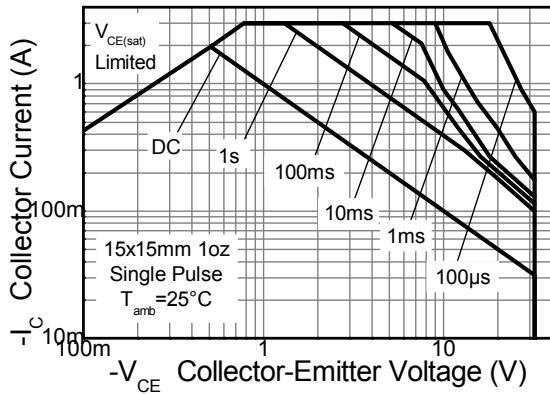
| Characteristic | Symbol | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage | V_{CBO} | -40 | V |
| Collector-Emitter Voltage | V_{CEO} | -32 | V |
| Emitter-Base Voltage | V_{EBO} | -6 | V |
| Continuous Collector Current | I_C | -2 | A |
| Peak Pulse Collector Current | I_{CM} | -3 | A |
| Base Current | I_B | -500 | mA |

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$ unless otherwise specified.)

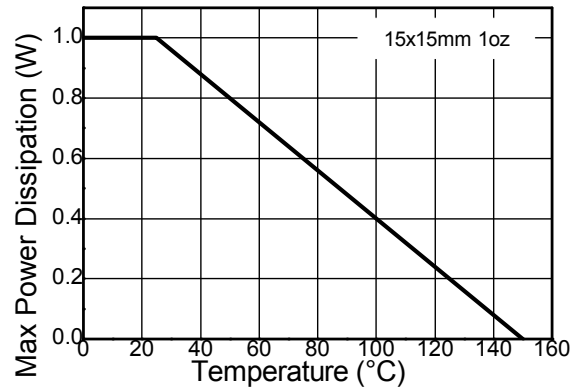
| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------------|--------------------|
| Power Dissipation (Note 5) | P_D | 1 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$ | 125 | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction to Leads (Note 6) | $R_{\theta JL}$ | 19 | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

- Notes:
5. For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

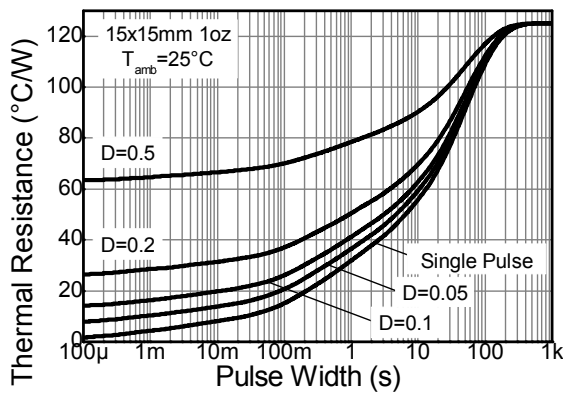
Thermal Characteristics and Derating Information



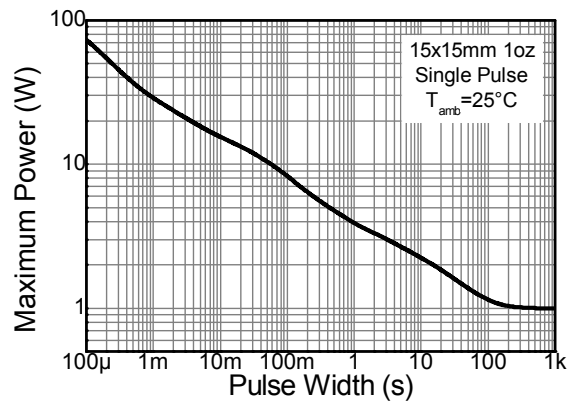
Safe Operating Area



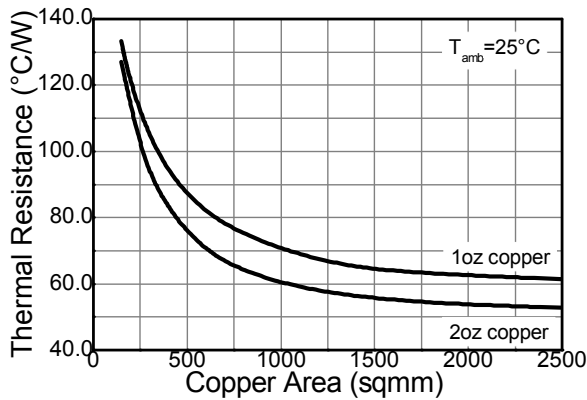
Derating Curve



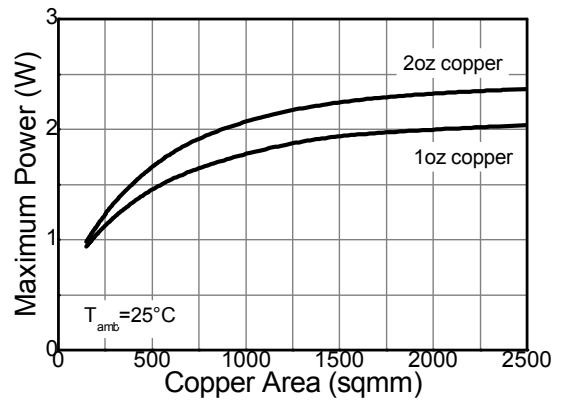
Transient Thermal Impedance



Pulse Power Dissipation



R_{TH} vs Area



P_D vs Area

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--------------------------------------|---------------|-----|-------|------|------|---|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Collector-Base Breakdown Voltage | BV_{CBO} | -40 | — | — | V | $I_C = -100\mu\text{A}, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | BV_{CEO} | -32 | — | — | V | $I_C = -10\text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | BV_{EBO} | -6 | — | — | V | $I_E = -100\mu\text{A}, I_C = 0$ |
| Collector Cutoff Current | I_{CBO} | — | — | -100 | nA | $V_{CB} = -20\text{V}, I_E = 0$ |
| Emitter Cutoff Current | I_{EBO} | — | — | -100 | nA | $V_{EB} = -5\text{V}, I_C = 0$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | — | -0.35 | -0.8 | V | $I_C = -2\text{A}, I_B = -0.2\text{A}$ |
| DC Current Gain | 2DB1188P | 82 | — | 180 | — | $V_{CE} = -3\text{V}, I_C = -0.5\text{A}$ |
| | 2DB1188Q | 120 | — | 270 | — | |
| | 2DB1188R | 180 | — | 390 | — | |
| SMALL SIGNAL CHARACTERISTICS | | | | | | |
| Current Gain-Bandwidth Product | f_T | — | 120 | — | MHz | $V_{CE} = -5\text{V}, I_C = -0.1\text{A}, f = 30\text{MHz}$ |
| Output Capacitance | C_{obo} | — | 20 | — | pF | $V_{CB} = -10\text{V}, f = 1\text{MHz}$ |

Notes: 7. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

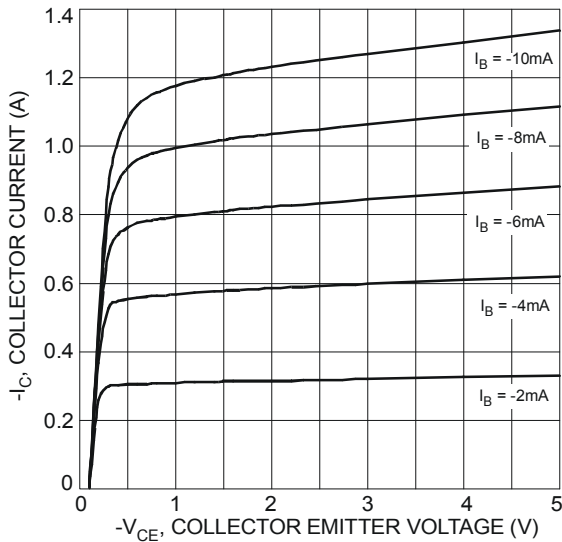


Figure 1. Typical Collector Current vs. Collector-Emitter Voltage

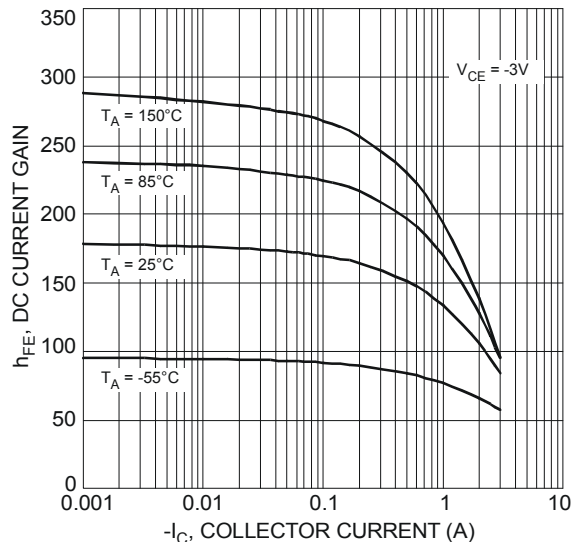


Figure 2. Typical DC Current Gain vs. Collector Current (2DB1188Q)

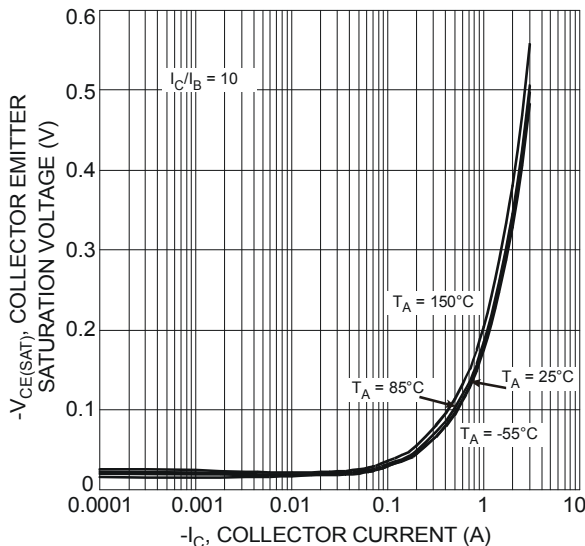


Figure 3. Typical Collector-Emitter Saturation Voltage vs. Collector Current

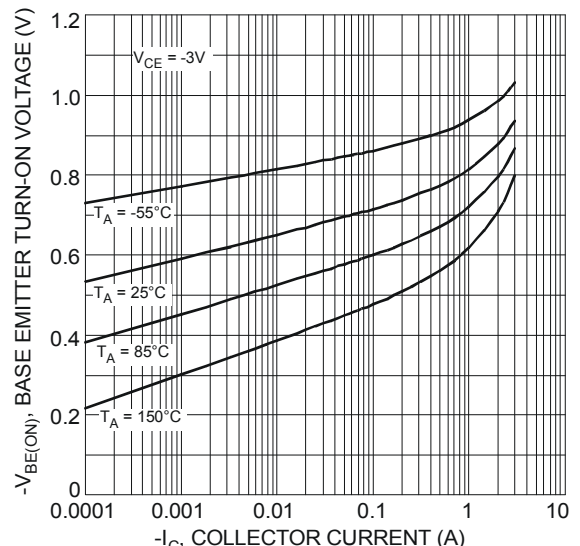


Figure 4. Typical Base-Emitter Turn-On Voltage vs. Collector Current

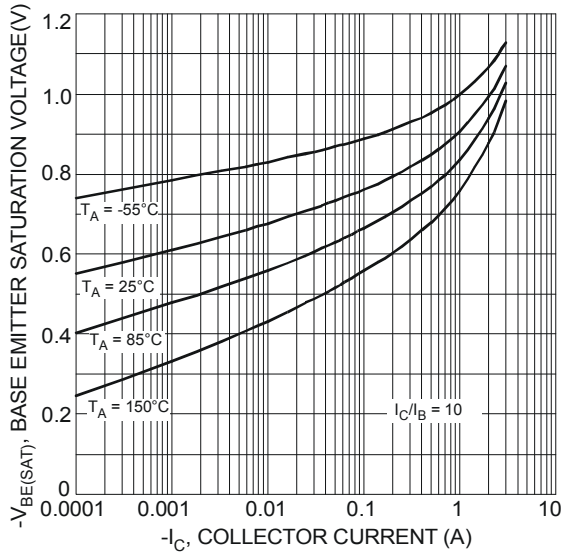


Figure 5. Typical Base-Emitter Saturation Voltage vs. Collector Current

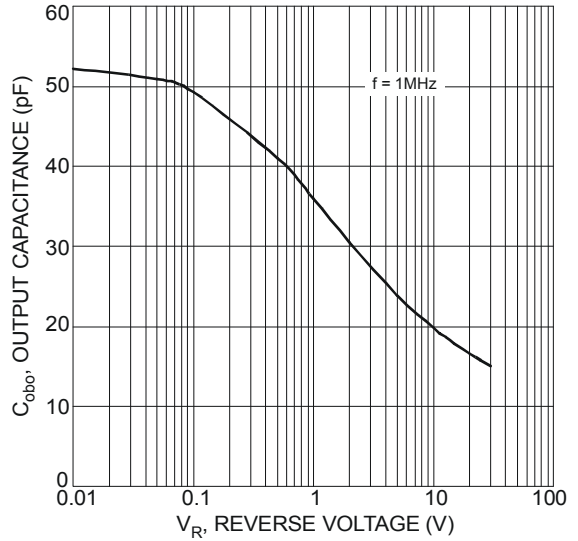


Figure 6. Typical Output Capacitance Characteristics

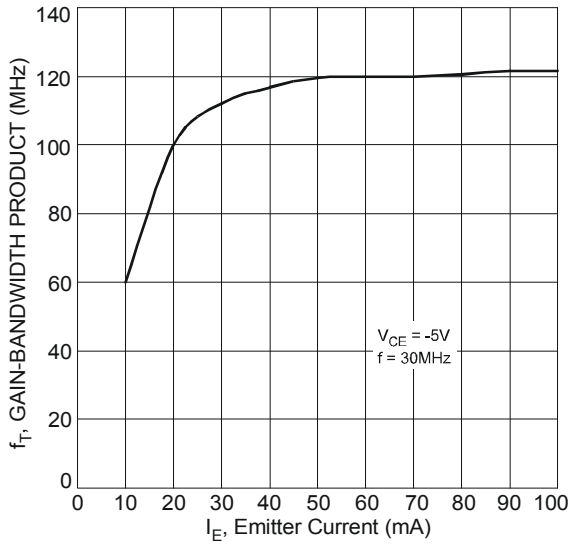
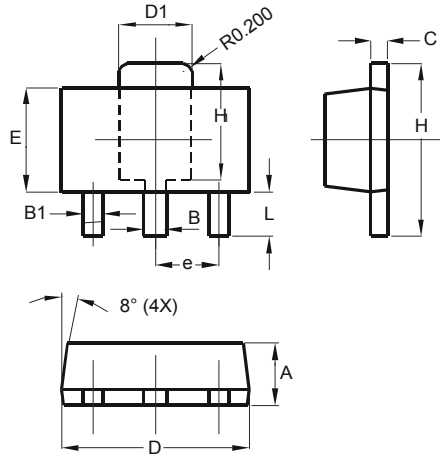


Figure 7. Typical Gain-Bandwidth Product vs. Emitter Current

Package Outline Dimensions

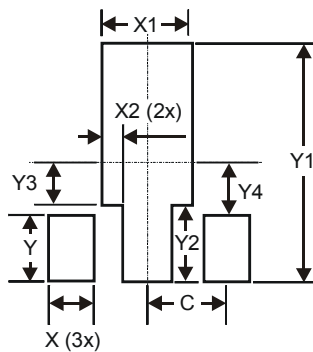
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT89 | | |
|----------------------|----------|------|
| Dim | Min | Max |
| A | 1.40 | 1.60 |
| B | 0.44 | 0.62 |
| B1 | 0.35 | 0.54 |
| C | 0.35 | 0.44 |
| D | 4.40 | 4.60 |
| D1 | 1.62 | 1.83 |
| E | 2.29 | 2.60 |
| e | 1.50 Typ | |
| H | 3.94 | 4.25 |
| H1 | 2.63 | 2.93 |
| L | 0.89 | 1.20 |
| All Dimensions in mm | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.900 |
| X1 | 1.733 |
| X2 | 0.416 |
| Y | 1.300 |
| Y1 | 4.600 |
| Y2 | 1.475 |
| Y3 | 0.950 |
| Y4 | 1.125 |
| C | 1.500 |

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